



## Features:

- High Voltage Power Transistor is a fast switching high voltage transistor, more specially intended for operating in industrial
- Collector-Emitter Sustaining Voltage  $V_{CEO(sus)}$  = 450V (Min.) BUW12A Low Collector-Emitter Saturation Voltage  $V_{CE(sat)}$  = 1.5V (Max.) at  $I_C$  = 6A,  $I_B$  = 1.2A

## **Maximum Ratings**

Characteristic	Symbol	BU406	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	450		
Collector-Emitter Voltage (V <sub>BE</sub> = 0)	V <sub>CES</sub>	1,000	000 V	
Emitter-Base Voltage	V <sub>EBO</sub>	9		
Collector Current-Continuous -Peak	I <sub>C</sub>	8 20	А	
Base Current-Continuous	I <sub>B</sub>	4		
Total Power Dissipation at T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	125 0.833	W W/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

## **Thermal Characteristics**

Characteristic	Symbol	Max.	Unit
Thermal Resistance Junction to Case	$R_{ hetajc}$	1.2	°C/W





## Electrical Characteristics ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min.	Max.	Unit	
OFF Characteristics						
Collector-Emitter Sustaining Voltage $I_C = 100$ mA, $I_B = 0$ , L = 25mH	e (1) BUW12A	V <sub>CEO(sus)</sub>	200	-	V	
Collector Cut off Current V <sub>CE</sub> = 1,000V, V <sub>BE</sub> = 0	BUW12A					
Emitter Cut off Current $V_{EB} = 9V$ , $I_{C} = 0$		I <sub>EBO</sub>	-	10	mA	
ON Characteristics (1)		•	•	•	•	
Collector-Emitter Saturation Voltage $I_C = 6A$ , $I_B = 1.2A$		V <sub>CE (sat)</sub>	-	1.5	V	
Base-Emitter Saturation Voltage $I_C = 6A$ , $I_B = 1.2A$		V <sub>BE(sat)</sub>	-			
Switching Characteristics					•	
Turn On Time	V = 240V I- = 6A	t <sub>on</sub>	-	1		
Storage Time	$V_{CC} = 240V, I_{C} = 6A$ B1 = 1.2A, $I_{B2} = -1.2A$	t <sub>s</sub>	-	4	μs	
Fall Time		t <sub>f</sub>	-	0.8	]	

(1) Pulse Test: Pulse Width = 300µs, Duty Cycle ≤2%

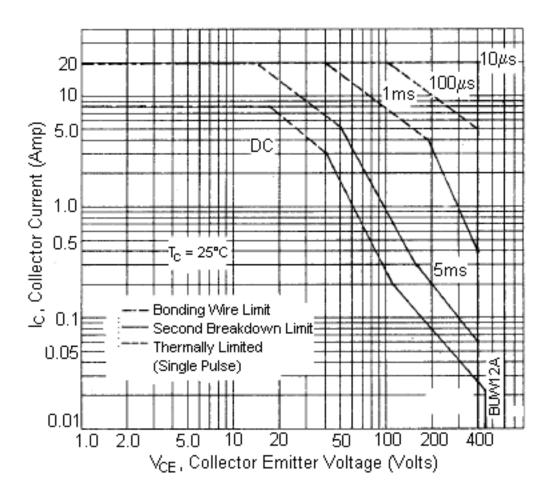
# Power Derating (strew) 125 100 100 25 50 25 Tc , Temperature (°C)

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## Active-Region Safe Operating Area (SOA)

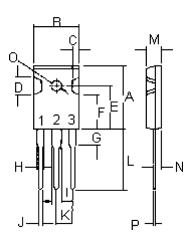


There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate  $I_C$ - $V_{CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of SOA curve is based on  $T_{J(PK)}$  = 175°C;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(PK)} \le 175$ °C. At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.







### **Pin Configuration:**

- 1. Base
- 2. Collector
- 3. Emitter

Dimensions	Min.	Max.
А	20.63	22.38
В	15.38	16.2
С	1.9	2.7
D	5.1	6.1
Е	14.81	15.22
F	11.72	12.84
G	4.2	4.5
Н	1.82	2.46
I	2.92	3.23
J	0.89	1.53
K	5.26	5.66
L	18.5	21.5
M	4.68	5.36
N	2.4	2.8
0	3.25	3.65
Р	0.55	0.7

Dimensions: Millimetres

## **Part Number Table**

Description	Part Number
Transistor, NPN, TO-247	BUW12A

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